Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-390-2009

# Maximum Power Dissipation Rating:

500.0 milliwatts

# **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# End Application:

Cv-3993/sys-2 e/i fscm 21877

## Features Provided:

Programmed and ultraviolet erasable and electrostatic sensitive

# Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

**Product Name:** 

32k x 8-bit prom

#### Voltage Rating And Type Per Characteristic:

4.5 volts applied and 5.5 volts applied

#### **Time Rating Per Chacteristic:**

70.00 nanoseconds access

# Memory Device Type:

Prom

# Hybrid Technology Type:

Monolithic

## Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

#### Unit Of Measure:

---

#### **Demilitarization:**

Yes - demil/mli

Fiig:

A458a0